	210	210	210	210	210	210	210
F	Regi	stration No :					
Tota	al Nu	umber of Pages	: 02				3.Tech T3l101
	210	3	rd Semester Regula	ar/Back Exan	nination 2018-19		210
	210	210	ANALÖG EL	ECTRÓNIC C	RCUITS	210	210
				CH : ECE, E1 ne : 3 Hours	IC		
				Marks : 100			
Α	nsw	er Question No	્ય. 1. (Part-1) which is	CODE : E667 compulsory	v. anv eight from	Part-II and anv	two
			fr	om Part-III.		•	
	210	² The	e figures in⁄the righ	nt hand [≥] marg	in indicate mark	S. 210	210
		-		Part- I			(2
Q1	a)		ype Questions (Ansv s a voltage controlled				(2 x 10)
	b)	Compare fixed b	ias and self-bias of Bo	JT.			
	c) d)		sion for total collector e of BJT amplifier if $V_{ m C}$				
	e) f)		equation. How it is us veen FET and BJT.	sed to design d	.c biasing of JFET?	210	210
	g)	An amplifier is	burst into oscillation	when the loo	p gain Aβ=1, but	for sustained	
	h)	oscillation Aβ>1,	Why so? inplification factor of a	transistor if its	nain is 100 2		
	i)	What do you me	an by CMRR? How it				
	j)	Op-Amp What do you me	ean by distortion in a	power amplifi	er? Which power	amplifier gives	
	210			210	210	210	210
				Part- II			
Q2	a)		Answer Type Questi acteristics of a JFET				(6 x 8)
	b)	Sketch the hybroutput impedance			the relations of g	ain, input and	
	-	•	ency response of BJT	·	210	210	210
	d) e)	magnitude of A	eral feedback systen lecreases by 20%, wh rating is selected in a	at is the corres	sponding % change		
	f)		e configuration and ex	•			
	g)	Find the input re	sistance, output resist	ance of an am	plifier that employs	voltage series	
	ħ)	feedback. Derive the condition	ions of oscillation in a	Wein-bridge o	escillator. ²¹⁰	210	210
	i)		np phase shift oscilla	-		r frequency of	
	:\	oscillation.			•	. ,	
	j) V		Amp can be used for	•		wod? Find the	
	k)		follower circuit. What Determine the voltage				
	I) 210	The pinch -off vo	oltage of a p-channel uch that a saturated o	JFET is V _p =5V	and I_{DSS} =- mA. Th		210

Part-III Long Answer Type Questions (Answer Any Two out of Four) Q3 a) Explain the frequency response of BJT amplifier. (8) Sketch the CE and CB hybrid equivalent model, given $I_{E(dc)}$ =1.2 mA, β =120 and r_0 =40 (8) KΩ. Q4 Briefly explain the principle and operation of N-channel and P-channel MOSFET with (16)its transfer characteristics. State and explain the Barkhausen criterion for sustained oscillation. Discuss its (8) Q5 importance in operation of an oscillator circuit. b) Describe Miller's effect and derive an equation for Miller input and output capacitance. (8) Q6 Draw the circuit diagram of a class-A transformer coupled power amplifier using an (16)npntransistor. This amplifier drives a 16 ohm speaker through a 4:1 transformer, using a power supply of V_{CC} =36V, the circuits delivers 2 watts to the load. Calculate a)AC power across transformer primary b)AC voltage across the load c)the RMS value of load current